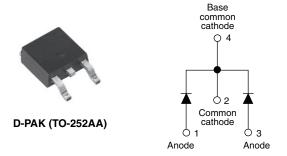
## VS-MBRD650CT-M3, VS-MBRD660CT-M3

Vishay Semiconductors

## High Performance Schottky Rectifier, 2 x 3 A



PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I <sub>F(AV)</sub>	2 x 3 A				
$V_{R}$	50 V, 60 V				
V <sub>F</sub> at I <sub>F</sub>	0.65 V				
I <sub>RM</sub>	15 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	6 mJ				

### **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



**FREE** 

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **DESCRIPTION**

The VS-MBRD650CT-M3, VS-MBRD660CT-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	6	А			
V <sub>RRM</sub>		50/60	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	490	А			
V <sub>F</sub>	3 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.65	V			
TJ	Range	-40 to +150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-MBRD650CT-M3 VS-MBRD660CT-M3 UNITS						
Maximum DC reverse voltage	$V_{R}$	50	60	V		
Maximum working peak reverse voltage	$V_{RWM}$	50	00	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	per leg	le,,,,	50 % duty cycle at T <sub>C</sub> = 128 °C, rectangular waveform		3.0	
See fig. 5	per device	I <sub>F(AV)</sub>			6	Α
Maximum peak one cycle	.+		5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		490	A
non-repetitive surge current See fig. 7		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	75	
Non-repetitive avalanche e	nergy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 12 mH		6	mJ
Repetitive avalanche curre	nt per leg	$I_{AR}$ Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		0.6	А	



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1		3 A	T <sub>.1</sub> = 25 °C	0.7	V	
	V <sub>FM</sub> <sup>(1)</sup>	6 A	1 1j = 25 C	0.9		
		3 A	T <sub>.1</sub> = 125 °C	0.65		
		6 A	1j = 125 C	0.85		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V Dated V	0.1	mA	
See fig. 2	IRM ('')	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	15		
Typical junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		145	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to +150	°C	
Maximum thermal resistance,	per leg	D	DC operation	6		
junction to case	per device	$R_{thJC}$	See fig. 4	3	°C/W	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		80	5, 11	
Approximate weight				0.3	g	
Approximate weight				0.01	OZ.	
Marking device			Consist do D. DAIX (similar to TO 252AA)	MBRD65	50CT	
			Case style D-PAK (similar to TO-252AA)	MBRD660CT		

### Note

$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



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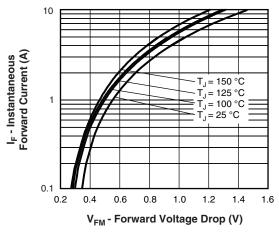


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

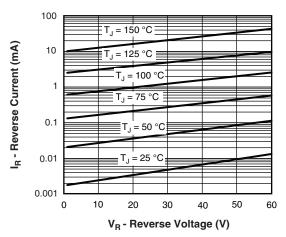


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

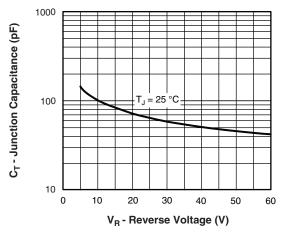


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

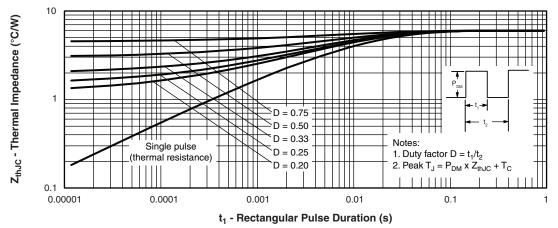
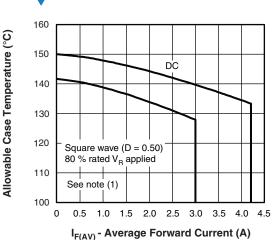


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

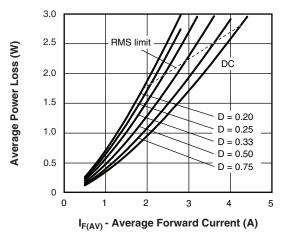


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

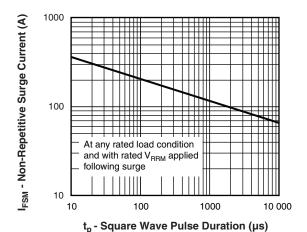


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

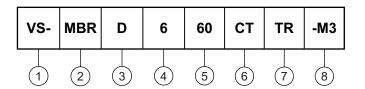
### Note

## VS-MBRD650CT-M3, VS-MBRD660CT-M3

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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Schottky MBR series

3 - D = TO-252AA (D-PAK)

4 - Current rating (6 = 6 A)

- Voltage ratings

- CT = Center tap (dual)

60 = 60 V

50 = 50 V

o or - center tap (d

7 - • None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBRD650CT-M3	75	3000	Antistatic plastic tube				
VS-MBRD650CTTR-M3	2000	2000	13" diameter reel				
VS-MBRD650CTTRL-M3	3000	3000	13" diameter reel				
VS-MBRD650CTTRR-M3	3000	3000	13" diameter reel				
VS-MBRD660CT-M3	75	3000	Antistatic plastic tube				
VS-MBRD660CTTR-M3	2000	2000	13" diameter reel				
VS-MBRD660CTTRL-M3	3000	3000	13" diameter reel				
VS-MBRD660CTTRR-M3	3000	3000	13" diameter reel				

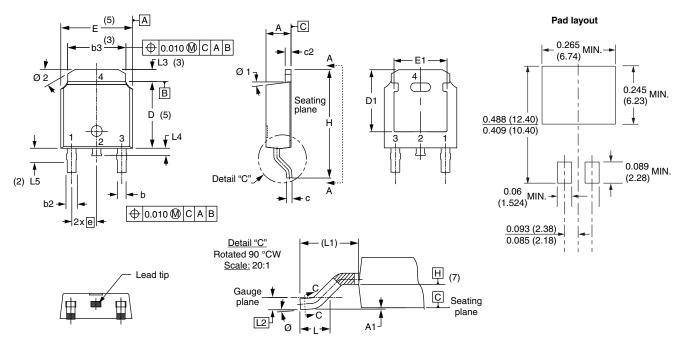
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95627			
Part marking information	www.vishay.com/doc?95176			
Packaging information	www.vishay.com/doc?95033			



### Vishay Semiconductors

## D-PAK (TO-252AA) "M"

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	LLIMETERS INCHES		HES	NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	2.18	2.39	0.086	0.094		
A1	-	0.13	-	0.005		
b	0.64	0.89	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215	3	
С	0.46	0.61	0.018	0.024		
c2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245	5	
D1	5.21	-	0.205	-	3	
Е	6.35	6.73	0.250	0.265	5	
E1	4.32	-	0.170	-	3	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0° 10°		0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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